## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of:	)	being deposited with the United States Postal Service as first class mail in an
Said Mansour et al.	)	commissioner for Patents, Washington, D.C. 20231 on
Serial No. 09/744,793	)	(Date of Deposit) James B. Myers Jr.
I.A. Filing Date: 30 July 1999	)	Name of Registered Representative
LOW TEMPERATURE OXYGEN GAS SENS	OR)	Signature  Signature  Signature

INFORMATION DISCLOSURE STATEMENT

Hon. Commissioner for Patents Washington, D.C. 20231

Sir:

Submitted herewith on the attached Information Disclosure Citation form is a list of documents of which Applicants are aware which they believe may be material to the examination of this application, and in respect of which there may be a duty to disclose in accordance with 37 C.F.R. §1.56. Copies are not enclosed, in accordance with 37 C.F.R. §1.98(d), since they were previously cited by the Office in prior application PCT/US99/17422, which is relied upon for an earlier filing date. However, if it would assist the Examiner to have separate copies of the listed references for this application, Applicants will be happy to supply such copies upon request.

This Statement is being submitted before the first Office Action on the merits, and, therefore, it is believed that no fee is due. Should any fee be required, however, please charge such fee to Deposit Account No. 23-3030, but not to include the payment of issue fees which are or may become due.

Respectfully submitted,

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INFORMATION DISCLOSURE	ATTY. DOCKET NO. 7024-499	SERIAL NO. 09/486,301	
CITATION (Use s veral sheets if necessary)	APPLICANT Said Mansour et al.		
Page 1 of 2	I.A. FILING DATE July 30, 1999	GROUP	7.00

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